



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	0.55Ω @ V _{GS} = 4.5V	0.75A
20V	0.75Ω @ V _{GS} = 2.5V	0.63A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected up to 1.5kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: Collector Dot
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @
- Weight: 0.001 grams (Approximate)

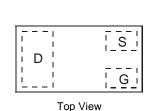


Notes:

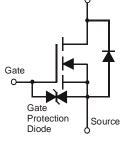


X1-DFN1006-3

Bottom View



Package Pin Configuration



Drain

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2400UFB-7	X1-DFN1006-3	3,000/Tape & Reel
DMN2400UFB-7B	X1-DFN1006-3	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information

DMN2400UFB-7	From date code 1527 (YYWW), this changes to: Top View Dot Denotes Drain Side Top View Bar Denotes Gate and Source Side
DMN2400UFB-7B	Top View Bar Denotes Gate and Source Side NB = Part Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 5) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +85°C	۱ _D	0.75 0.55	А
Continuous Drain Current (Note 5) V_{GS} = 2.5V	Steady State	T _A = +25°C T _A = +85°C	lo	0.63 0.45	А
Pulsed Drain Current (Note 6)			IDM	3	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	0.47	mW
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	258	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

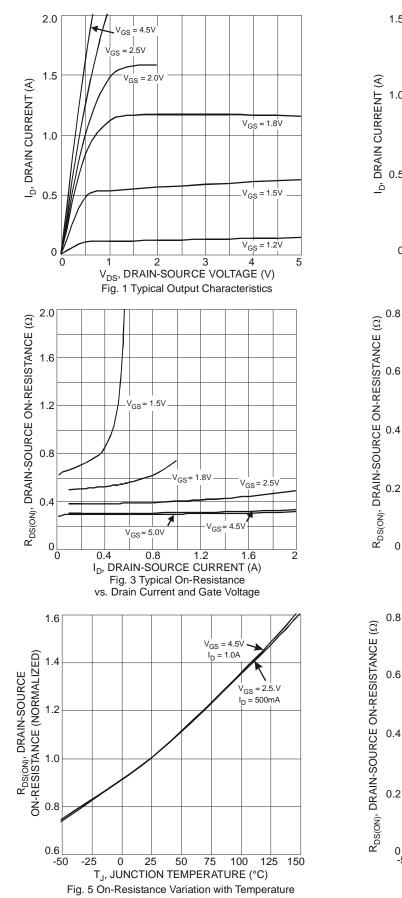
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

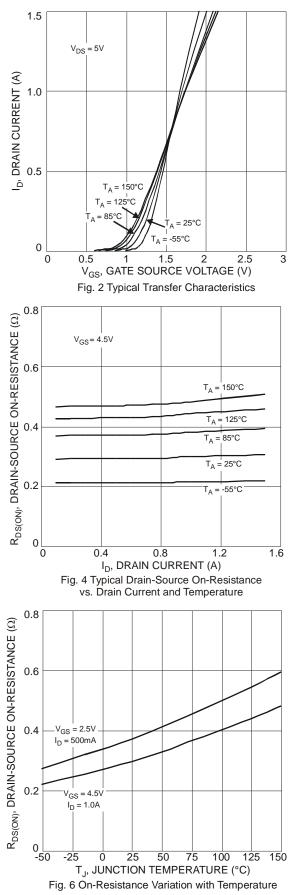
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}	-	-	100	nA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±1.0	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$	
Gate-Source Leakage	I _{GSS}	-	-	±50	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	0.5	-	0.9	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
		-	-	0.55		$V_{GS} = 4.5V, I_D = 600mA$	
Static Drain-Source On-Resistance	R _{DS (ON)}	-	-	0.75	Ω	$V_{GS} = 2.5V, I_D = 500mA$	
		-	-	0.9		$V_{GS} = 1.8V, I_D = 350mA$	
Forward Transfer Admittance	Y _{fs}	-	1.0	-	S	$V_{DS} = 10V, I_D = 400mA$	
Diode Forward Voltage (Note 7)	V _{SD}		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 150mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance		-	36.0	-	pF		
Output Capacitance		-	5.7	-	pF	V _{DS} = 16V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	4.2	-	pF	1 = 1.00012	
Total Gate Charge	Qg	-	0.5	-	nC		
Gate-Source Charge		-	0.07	-	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$	
Gate-Drain Charge	Q _{gd}	-	0.1	-	nC	$I_D = 250 \text{mA}$	
Turn-On Delay Time	t _{D(on)}	-	4.11	-	ns		
Turn-On Rise Time Turn-Off Delay Time		-	3.82	-	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$	
		-	14.8	-	ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$ $I_{D} = 200mA$	
Turn-Off Fall Time	t _{D(off)} t _f	-	9.6	-	ns		

5. Device mounted on FR-4 PCB, with minimum recommended pad layout. Notes:

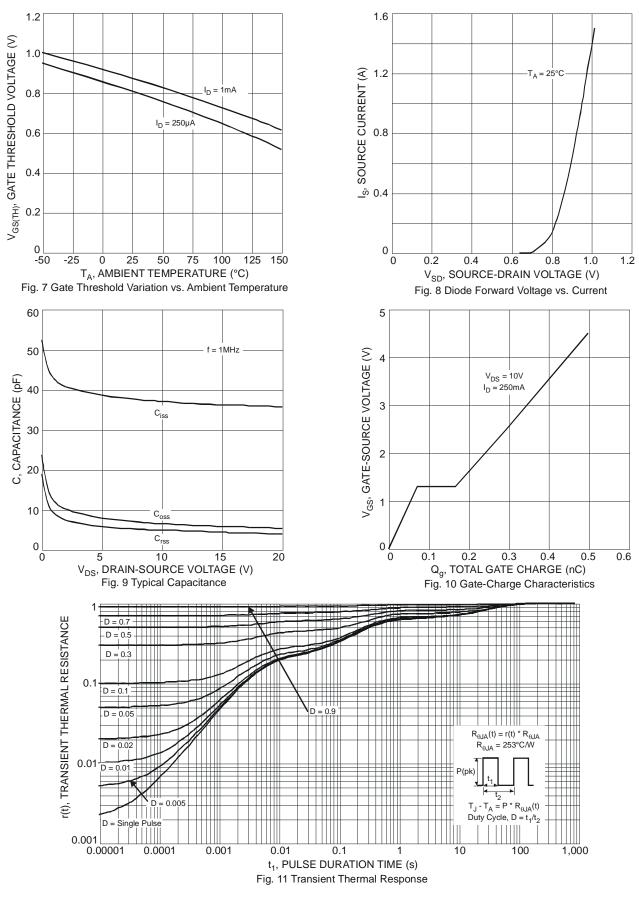
Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.







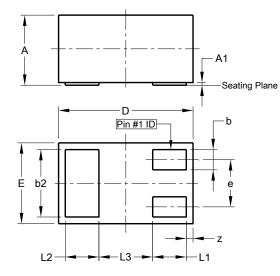






Package Outline Dimensions

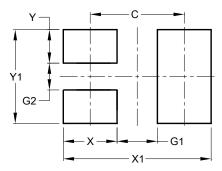
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X1-DFN1006-3						
Dim	Min	Max	Тур			
Α	0.47	0.53	0.50			
A1	0.00	0.05	0.03			
b	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95	1.075	1.00			
Е	0.55	0.675	0.60			
e	-	-	0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3	-	-	0.40			
Z	0.02	0.08	0.05			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Ý	0.25
Y1	0.70



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